



**THE DATASHEET OF  
ESD112B102ELSE6327XTSA1**



# TVS Diodes

Transient Voltage Suppressor Diodes

## ESD112-B1-02 Series

Bi-directional Ultra-low Capacitance ESD / Transient Protection Diode

ESD112-B1-02ELS  
ESD112-B1-02EL

## Data Sheet

Rev. 1.3, 2013-11-27  
Final

**Revision History: Rev.1.2, 2013-06-10**

Page or Item	Subjects (major changes since previous revision)
<b>Rev. 1.3, 2013-11-27: Final Data Sheet</b>	
	ESD112-B1-02EL Status change to final

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Last Trademarks Update 2010-10-26

# 1 Bi-directional Ultra-low Capacitance ESD / Transient Protection Diode

## 1.1 Features

- ESD / transient protection of RF signal lines according to:
  - IEC61000-4-2 (ESD):  $\pm 20$  kV (air/contact)
  - IEC61000-4-4 (EFT):  $\pm 40$  A (5/50 ns)
  - IEC61000-4-5 (surge):  $\pm 3$  A (8/20  $\mu$ s)
- Maximum working voltage:  $V_{RWM} \pm 5.3$  V
- Extremely low capacitance:  $C_L = 0.2$  pF (typical)
- Low clamping voltage:  $V_{CL} = 29$  V (typical) at  $I_{PP} = 16$  A
- Very low reverse current  $I_R < 1$  nA typ.
- Very small form factor down to  $0.62 \times 0.32 \times 0.31$  mm<sup>3</sup>
- Pb-free (RoHS compliant) and halogen free package



## 1.2 Application Examples

- ESD protection of sensitive RF signal lines, Bluetooth Class 2, Automated Meter Reading
- RF antenna protection, frontend module, GPS, mobile TV, FM radio, UWB

## 1.3 Product Description

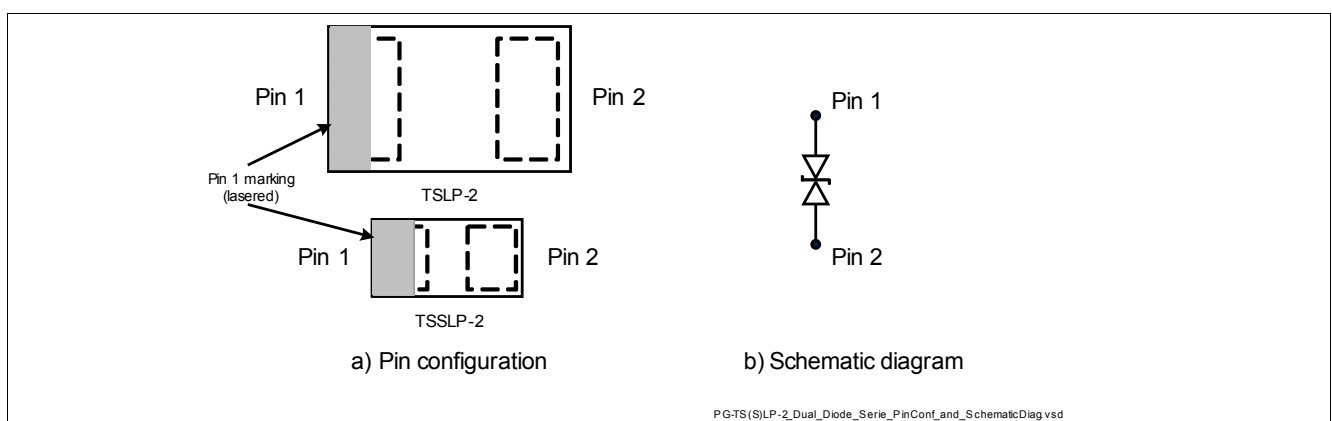


Figure 1-1 Pin Configuration and Schematic Diagram

Table 1-1 Ordering Information

Type	Package	Configuration	Marking code
ESD112-B1-02ELS	TSSLP-2-4	1 line, bi-directional	<u>I</u>
ESD112-B1-02EL	TSLP-2-20	1 line, bi-directional	TE



**Characteristics**
**Table 2-2 DC Characteristics at  $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise specified**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Reverse working voltage	$V_{RWM}$	-5.3	-	5.3	V	
Breakdown voltage	$V_{BR}$	7	-	-	V	$I_R = 1\text{ mA}$ , from pin 1 to pin 2, from pin 2 to pin 1
Reverse current	$I_R$	-	<1	50	nA	$V_R = 5.3\text{ V}$

**Table 2-3 RF Characteristics at  $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise specified**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Diode capacitance	$C_L$	-	0.23	0.4	pF	$V_R = 0\text{ V}, f = 1\text{ MHz}$
		-	0.2	0.4		$V_R = 0\text{ V}, f = 1\text{ GHz}$
Series inductance	$L_S$	-	0.2	-	nH	ESD112-B1-02ELS
		-	0.4	-		ESD112-B1-02EL

**Table 2-4 ESD Characteristics at  $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise specified**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Clamping voltage <sup>2)</sup>	$V_{CL}$	-	29	-	V	$I_{TLP} = 16\text{ A}$
		-	44	-		$I_{TLP} = 30\text{ A}$
Clamping voltage <sup>1)</sup>		-	11	17		$I_{PP} = 1\text{ A}$
		-	15	21		$I_{PP} = 3\text{ A}$
Dynamic resistance <sup>2)</sup>	$R_{DYN}$	-	1	-	$\Omega$	

1)  $I_{PP}$  according to IEC61000-4-5 ( $t_p = 8/20\text{ }\mu\text{s}$ )

2) Please refer to Application Note AN210 [4]. TLP parameter:  $Z_0 = 50\text{ }\Omega$ ,  $t_p = 100\text{ ns}$ ,  $t_r = 300\text{ ps}$ , averaging window:  $t_1 = 30\text{ ns}$  to  $t_2 = 60\text{ ns}$ , extraction of dynamic resistance using least squares fit of TLP characteristics between  $I_{TLP1} = 10\text{ A}$  and  $I_{TLP2} = 40\text{ A}$ .

2.2 Typical Characteristics at  $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise specified

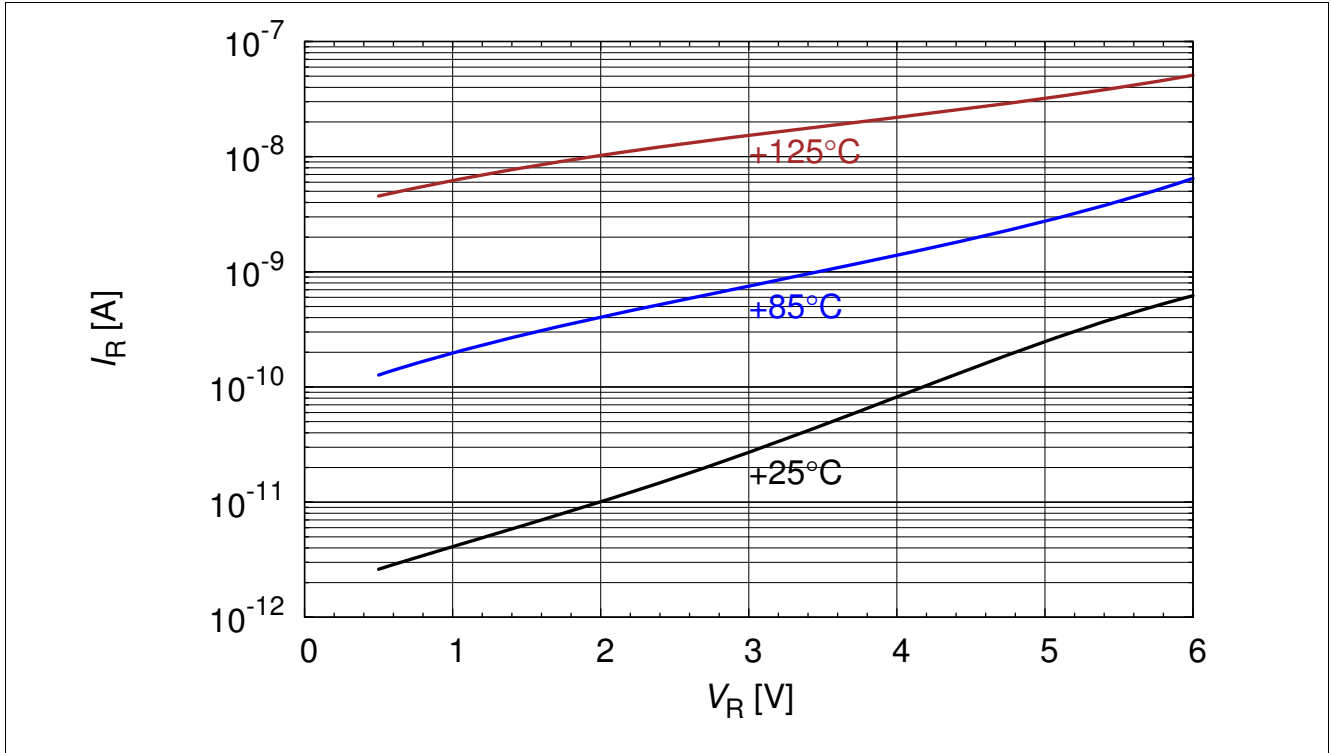


Figure 2-2 Reverse current:  $I_R = f(V_R)$ ,  $T_A = \text{parameter}$

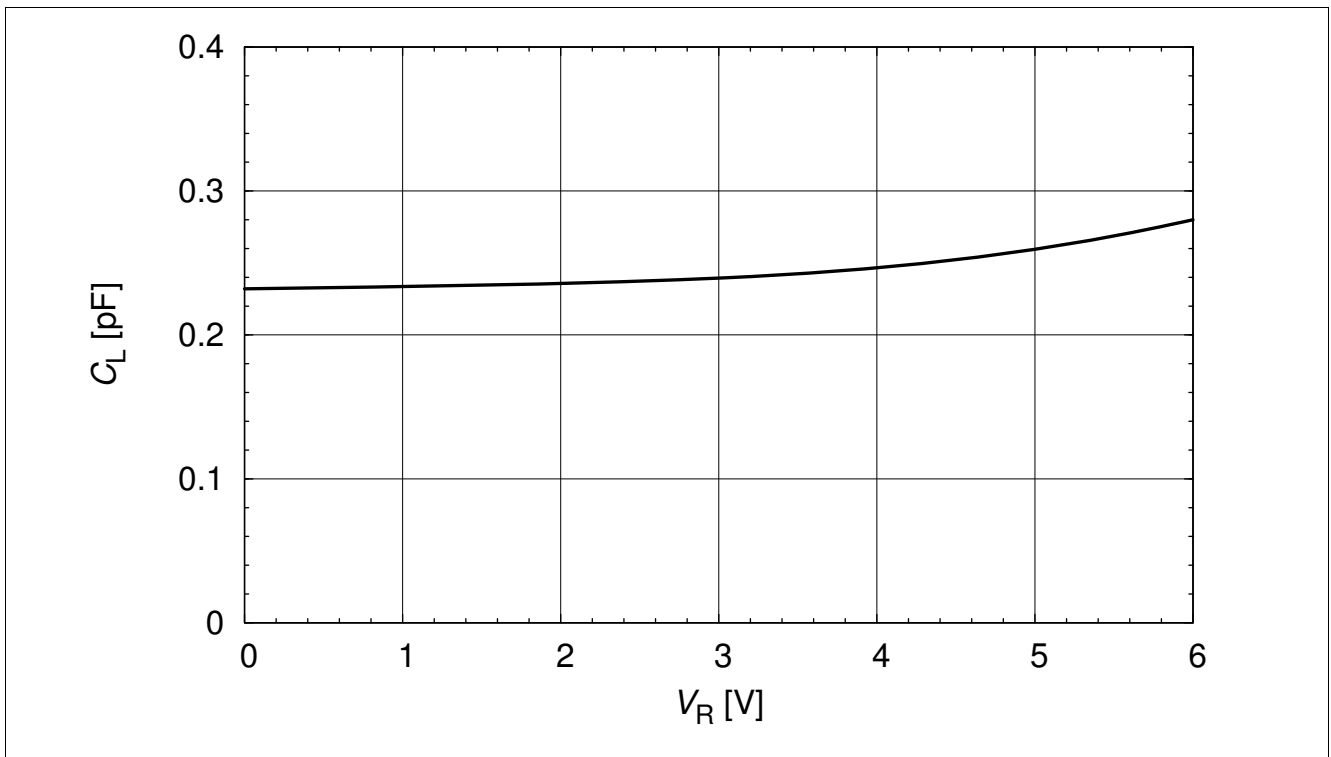


Figure 2-3 Line capacitance:  $C_L = f(V_R)$ ,  $f = 1\text{ MHz}$

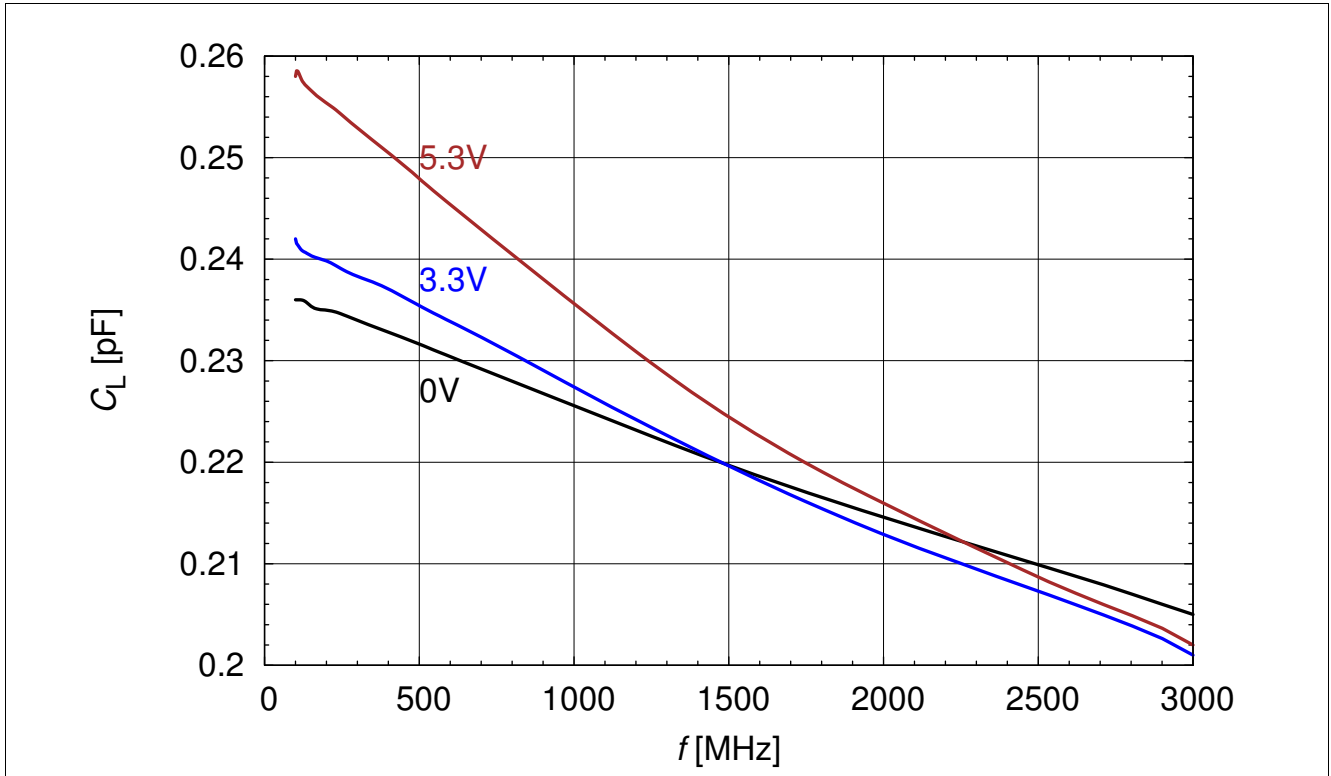


Figure 2-4 Line capacitance:  $C_L = f(f)$ ,  $V_R = \text{parameter}$

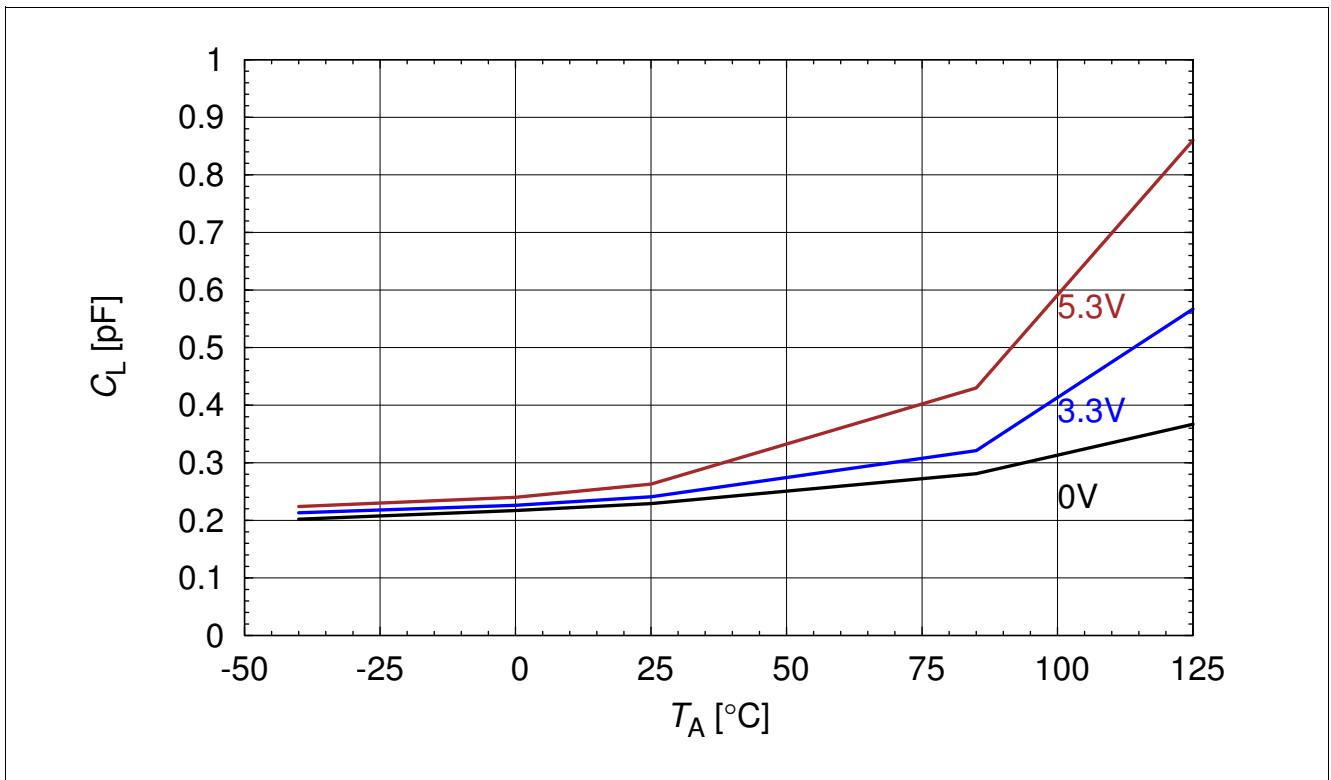


Figure 2-5 Line capacitance:  $C_L = f(T_A)$ ,  $V_R = \text{parameter}$

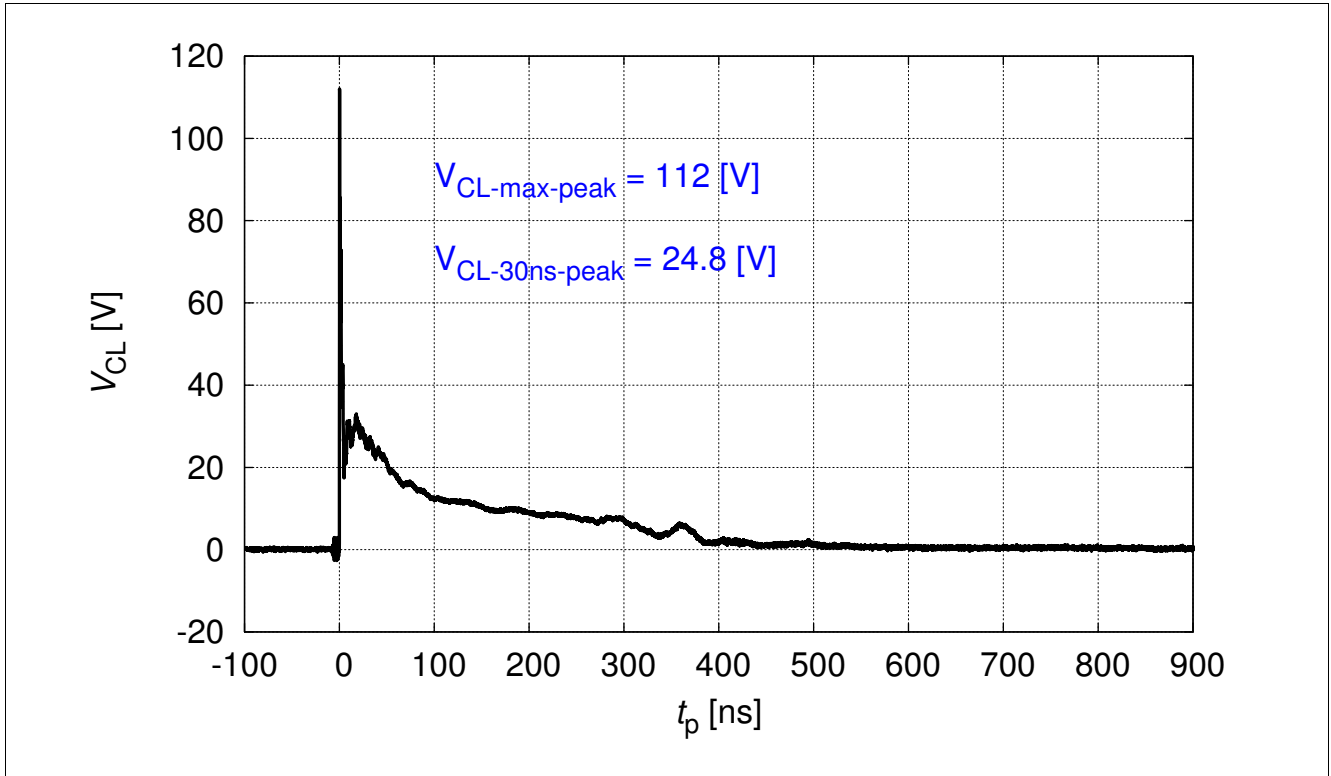


Figure 2-6 IEC61000-4-2  $V_{CL} = f(t)$ , 8 kV positiv pulse from pin 1 to pin 2

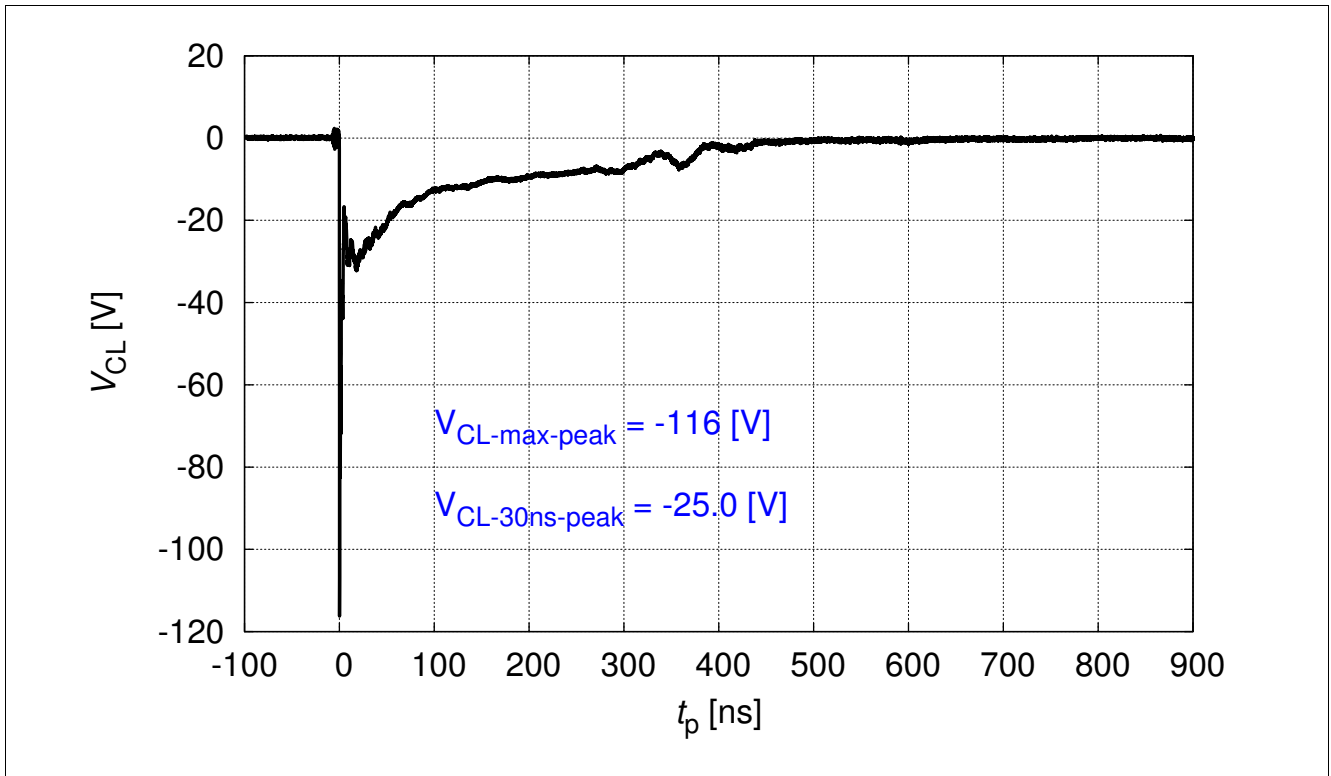


Figure 2-7 IEC61000-4-2  $V_{CL} = f(t)$ , 8 kV negativ pulse from pin 1 to pin 2

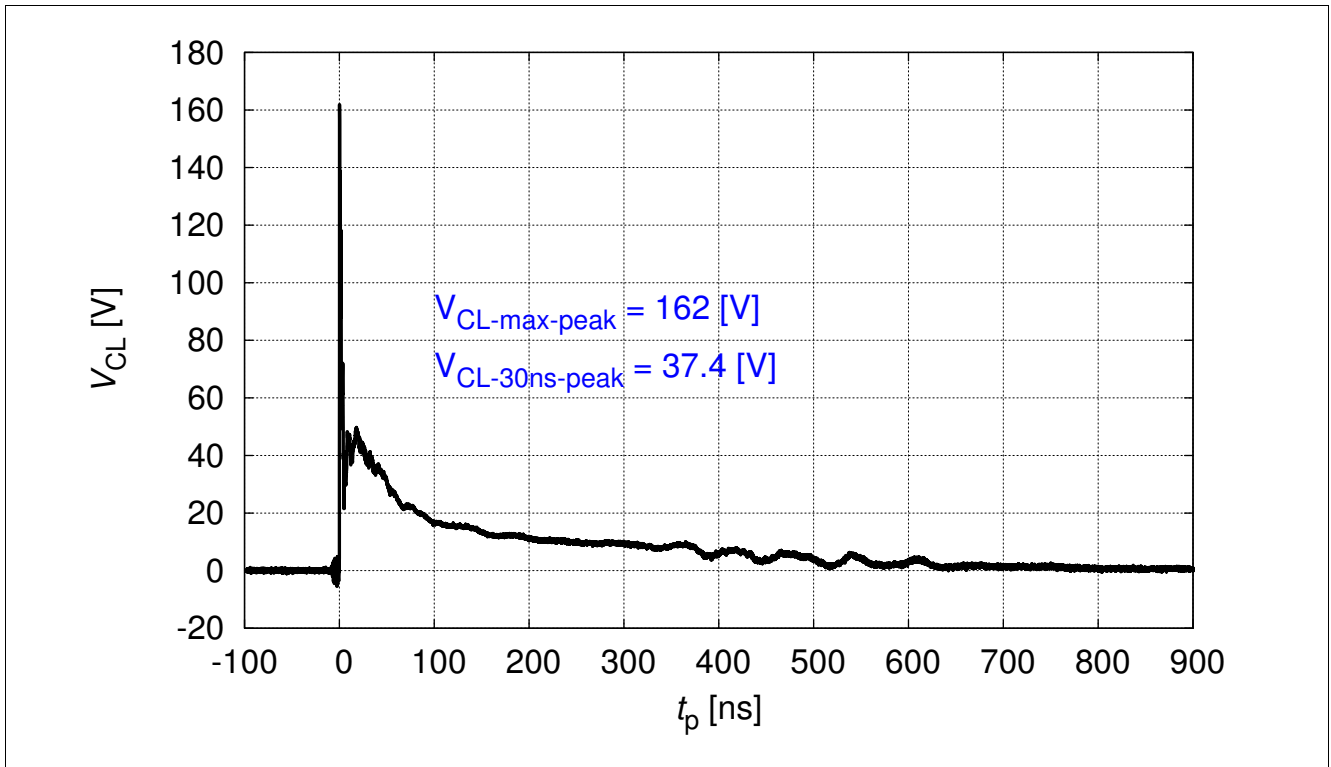


Figure 2-8 IEC61000-4-2  $V_{CL} = f(t)$ , 15 kV positiv pulse from pin 1 to pin 2

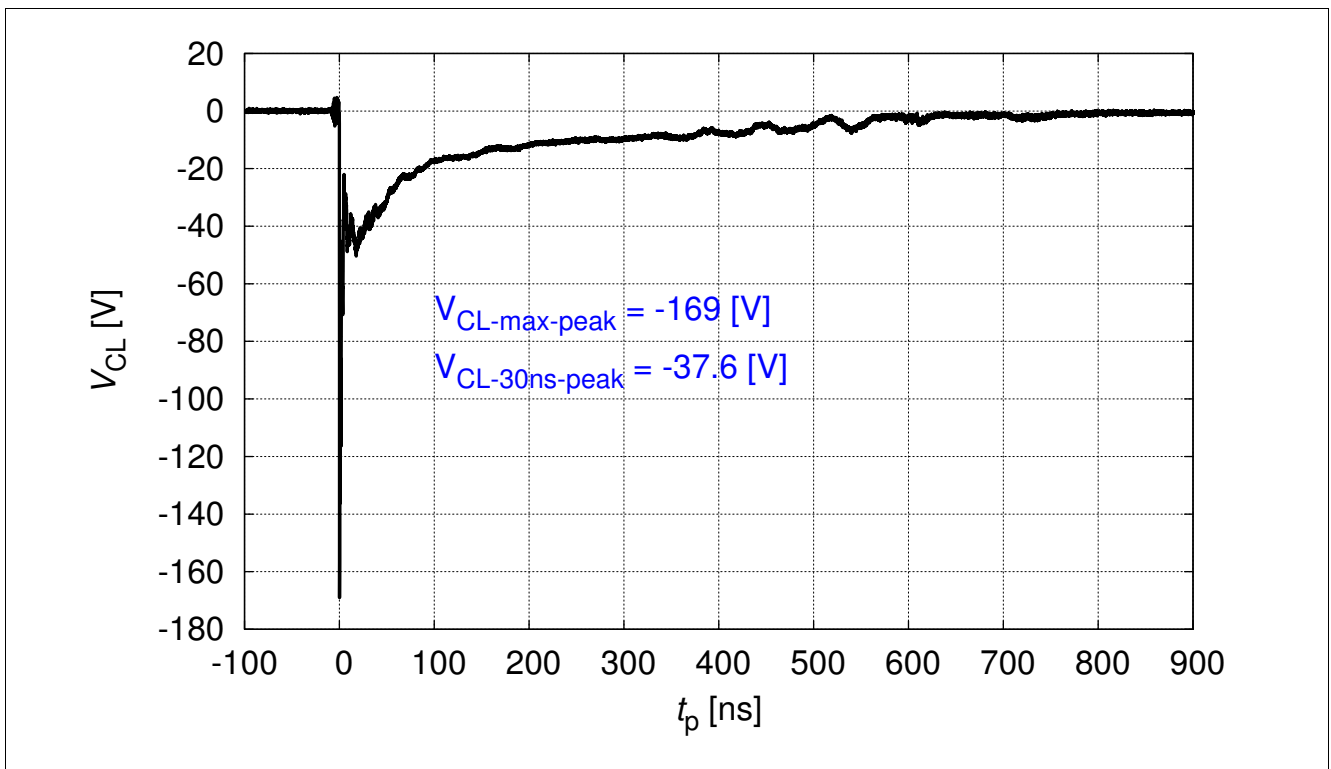


Figure 2-9 IEC61000-4-2  $V_{CL} = f(t)$ , 15 kV negativ pulse from pin 1 to pin 2

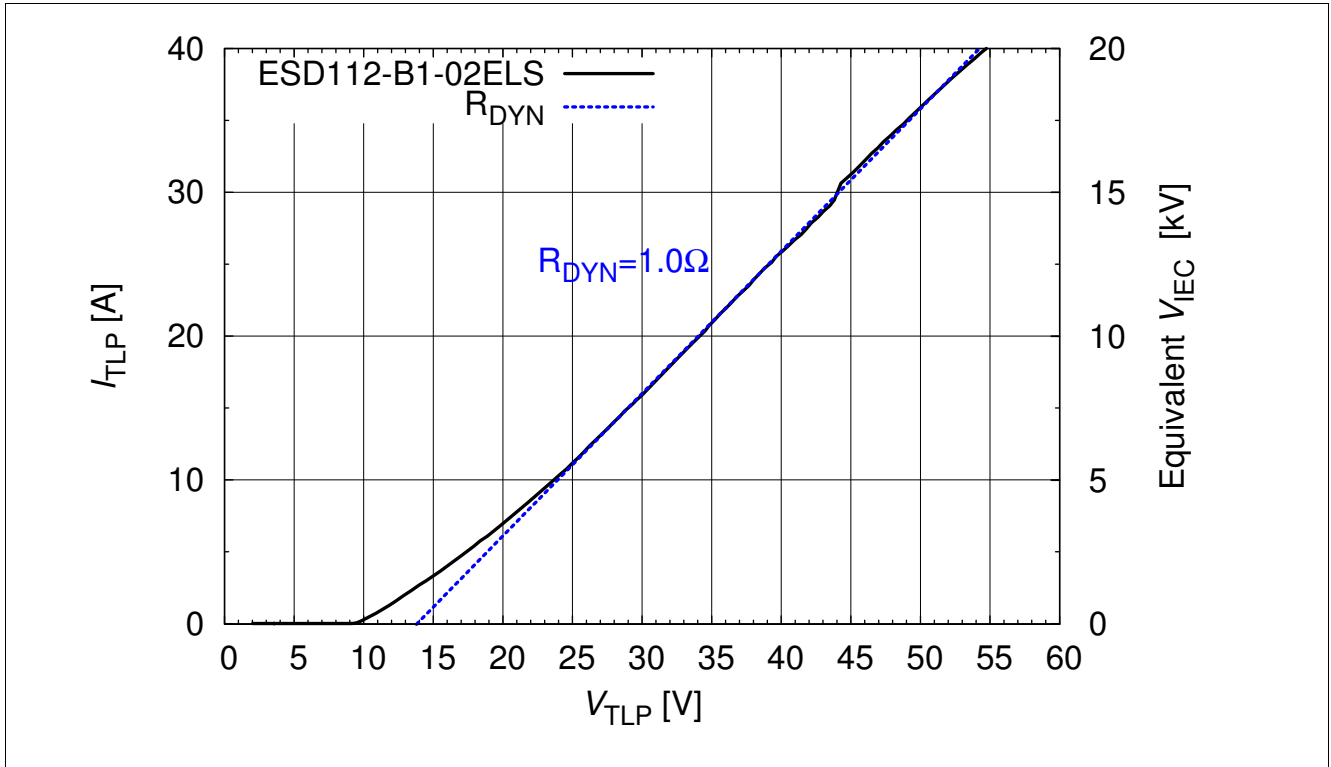


Figure 2-10 Clamping voltage :  $I_{TLP} = f(V_{TLP})$  [4]

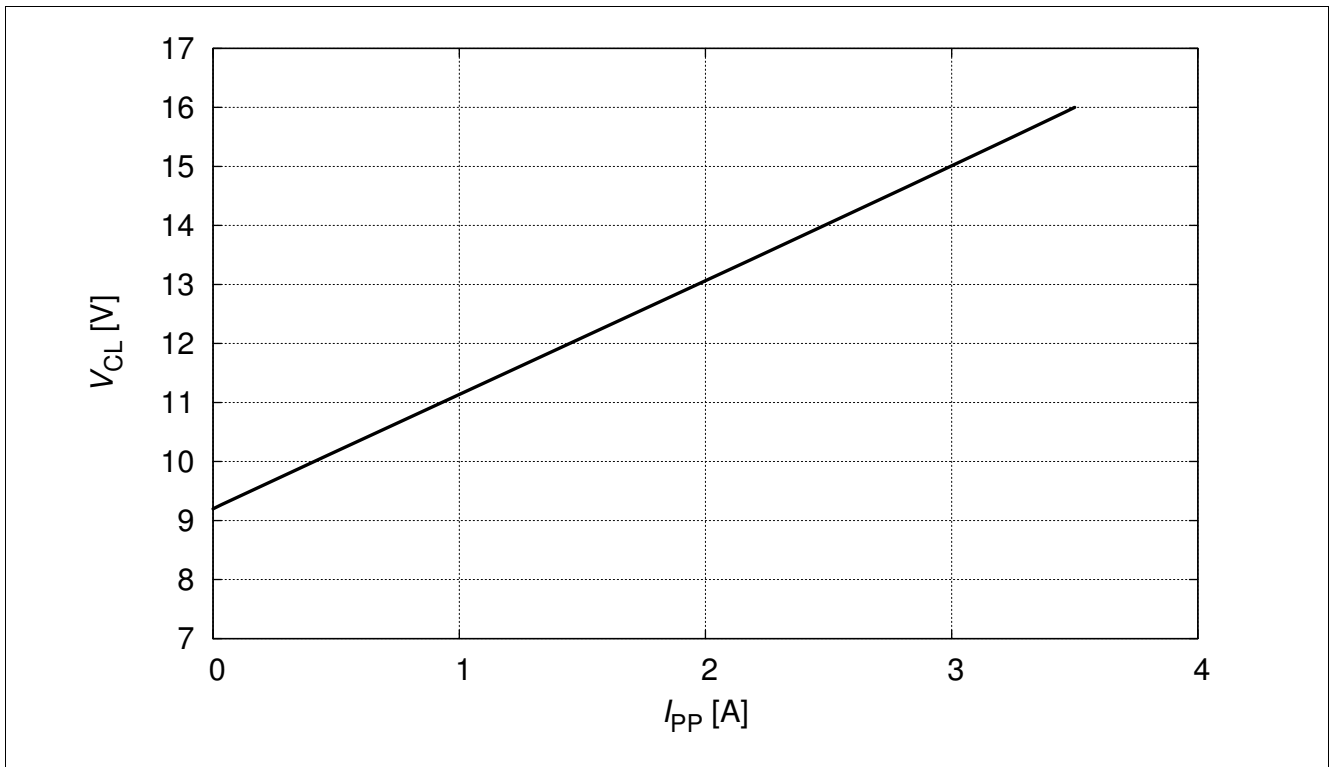


Figure 2-11 Clamp voltage:  $V_{CL} = f(I_{PP})$ ,  $t_p = 8/20 \mu s$

### 3 Application Information

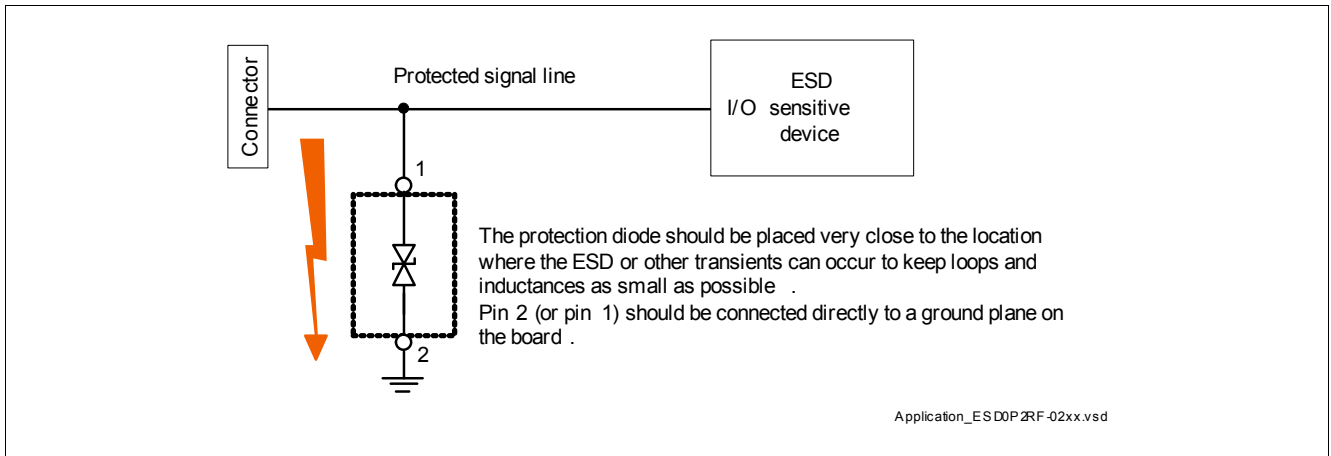


Figure 3-1 Single line, bi-directional ESD / Transient protection [1], [2]

## 4 Package Information

### 4.1 TSSLP-2-4 (mm) [5]

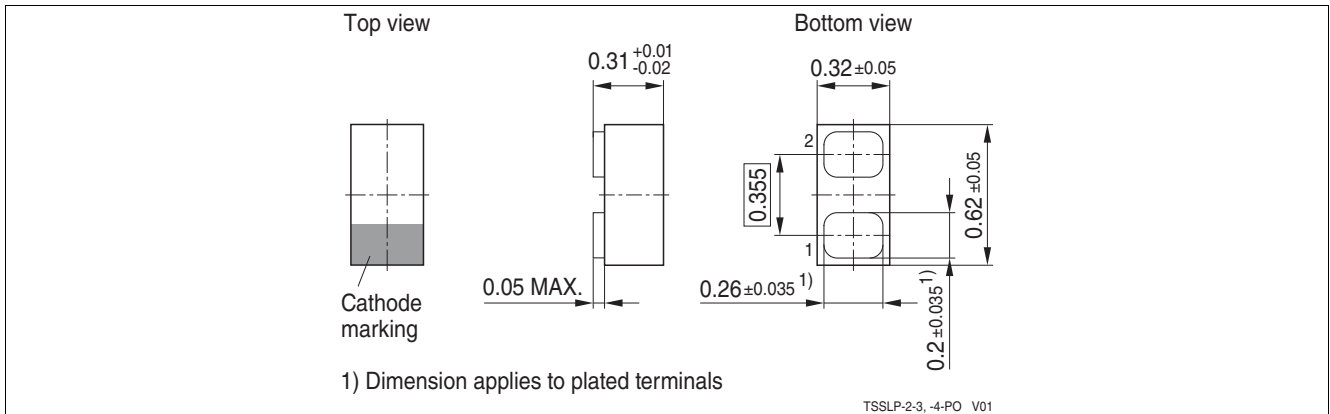


Figure 4-1 TSSLP-2-4 Package overview

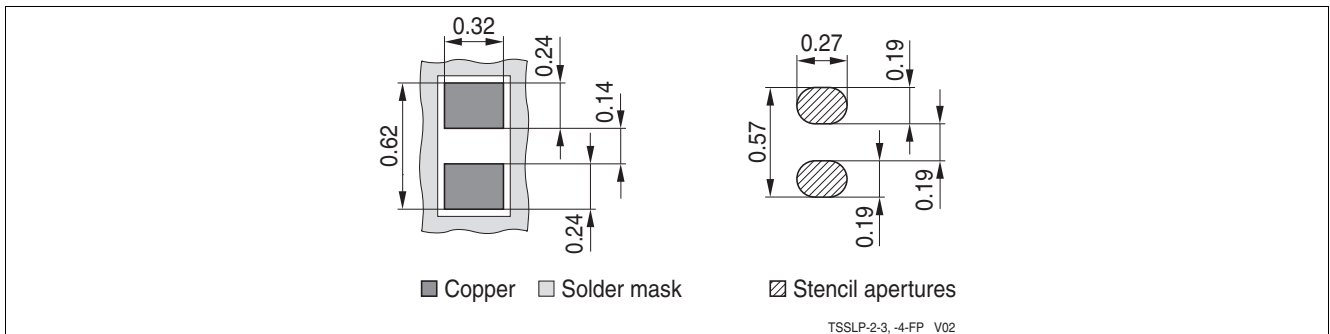


Figure 4-2 TSSLP-2-4: Footprint

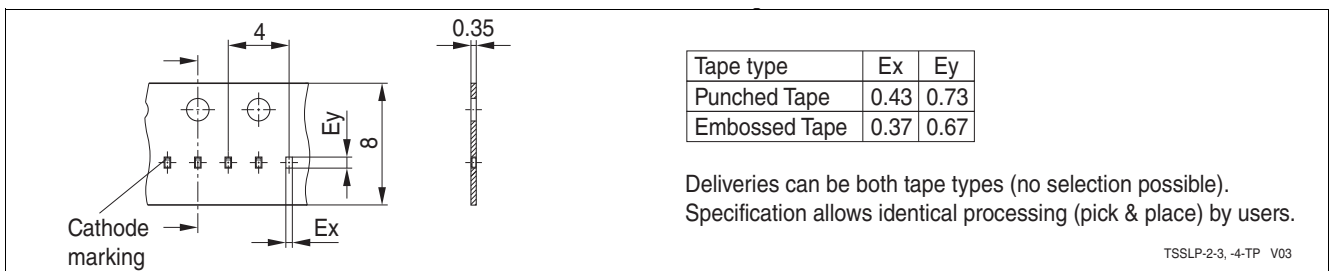


Figure 4-3 TSSLP-2-4: Packing

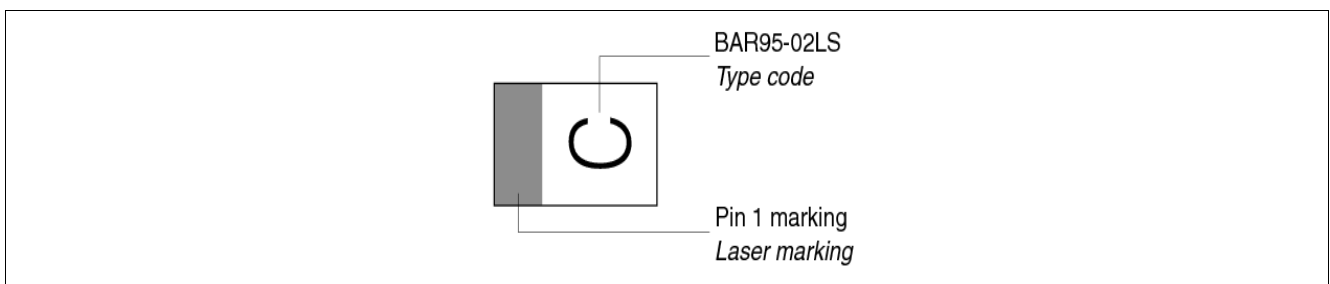


Figure 4-4 TSSLP-2-4: Marking (example)

4.2 TSLP-2-20 (mm) [5]

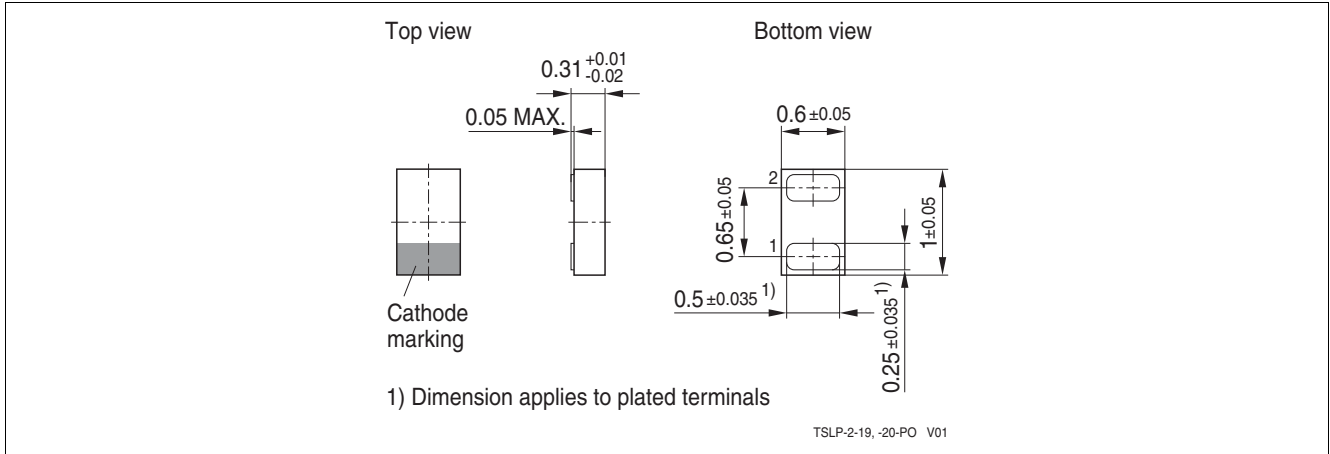


Figure 4-5 TSLP-2-20: Package overview

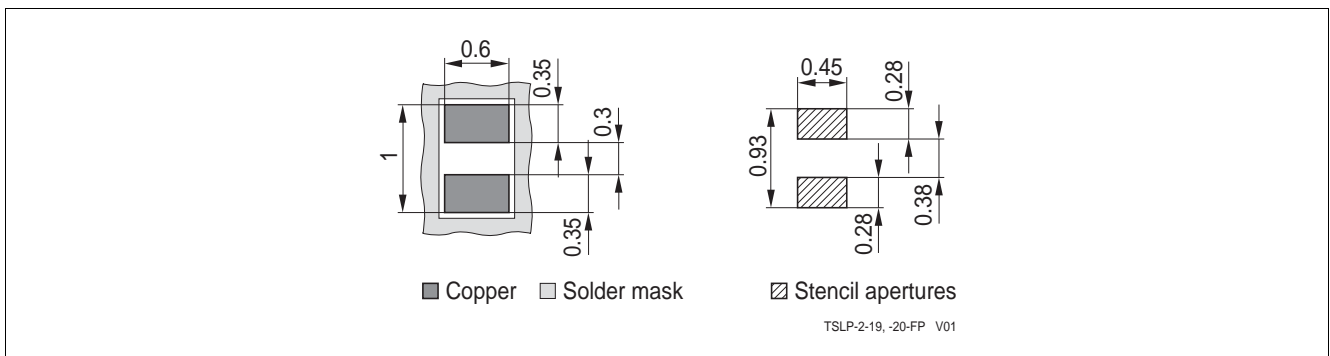


Figure 4-6 TSLP-2-20: Footprint

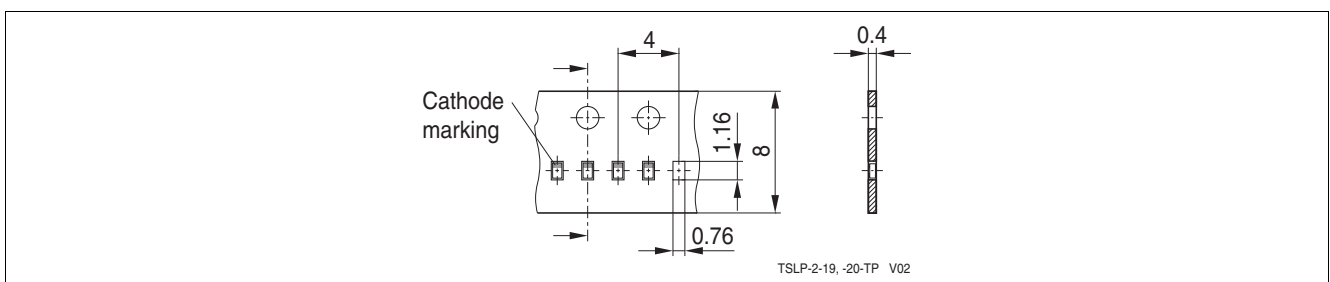


Figure 4-7 TSLP-2-20: Packing

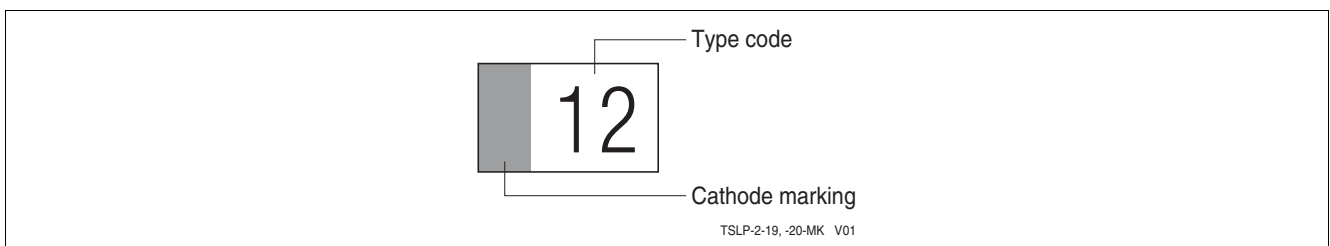


Figure 4-8 TSLP-2-20: Marking (example)

## References

- [1] Infineon AG - **Application Note AN167**: ESD Protection for Broadband LNA BGA728L7 for Portable and Mobile TV Applications
- [2] Infineon AG - **Application Note AN178**: ESD Protection for RF Antennas using Infineon ESD0P4RFL and ESD0P2RF-xx
- [3] Infineon AG - **Application Note AN200**: Low Cost FM Radio LNA using BFR340F for Mobile Phone Applications
- [4] Infineon AG - **Application Note AN210**: Effective ESD Protection Design at System Level using VF-TLP Characterization Methodology
- [5] Infineon AG - Recommendations for PCB Assembly of Infineon TSLP and TSSLP Packages

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